MP4021

High Power Switching Applications

Hammer Drive, Pulse Motor Drive and Inductive Load Switching

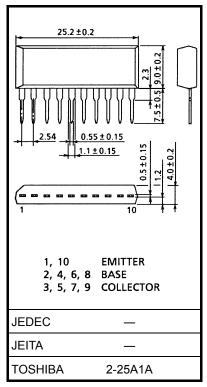
- Small package by full molding (SIP 10 pins)
- High collector power dissipation (4-device operation)
 PT = 4 W (Ta = 25°C)
- High collector current: IC(DC) = 2 A(max)
- High DC current gain: $h_{FE} = 2000$ (min) ($V_{CE} = 2 \text{ V}$, $I_{C} = 1 \text{ A}$)
- Zener diode included between collector and base.

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	85	V	
Collector-emitter voltage		V _{CEO}	100 ± 15	V	
Emitter-base voltage		V _{EBO}	8	V	
Collector current	DC	IC	2	Α	
	Pulse	I _{CP}	3		
Continuous base current		ΙΒ	0.5	Α	
Collector power dissipation (1-device operation)		PC	2.0	W	
Collector power dissipation (4-device operation)		PT	4.0	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	

Industrial Applications

Unit: mm

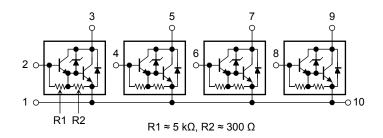


Weight: 2.1 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Array Configuration



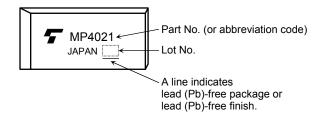
Characteristics	Symbol	Max	Unit	
Thermal resistance from junction to ambient	ΣR _{th (j-a)}	31.3	°C/W	
(4-device operation, Ta = 25°C)	3 (3)			
Maximum lead temperature for soldering purposes	TL	260	°C	
(3.2 mm from case for 10 s)				

Electrical Characteristics (Ta = 25°C)

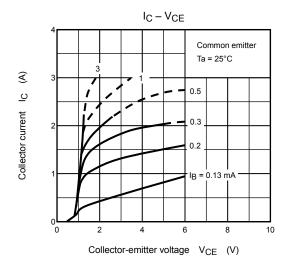
Charac	teristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 80 V, I _E = 0 A	_	_	10	μΑ
Collector cut-off current		I _{CEO}	V _{CE} = 80 V, I _B = 0 A	_	_	10	μΑ
Emitter cut-off current		I _{EBO}	V _{EB} = 8 V, I _C = 0 A	0.8	_	4.0	mA
Collector- emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _E = 0 A	85	100	115	V
DC current gain		h _{FE}	V _{CE} = 2 V, I _C = 1 A	2000	_	_	_
Saturation voltage	Collector-emitter	V _{CE} (sat)	I _C = 1 A, I _B = 1 mA	_	_	1.5	V
	Base-emitter	V _{BE} (sat)	I _C = 1 A, I _B = 1 mA	_	_	2.0	
Transition frequency		f _T	V _{CE} = 2 V, I _C = 0.5 A	_	100	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0 A, f = 1 MHz	_	20	_	pF
Switching time	Turn-on time	t _{on}	Output Input $B1$ $B1$ CC C	_	0.45	_	μs
	Storage time	t _{stg}		_	2.0	_	
	Fall time	t _f		_	0.4	_	

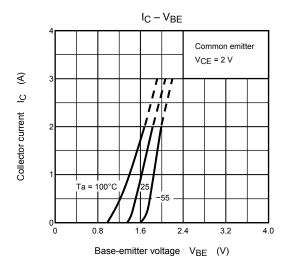
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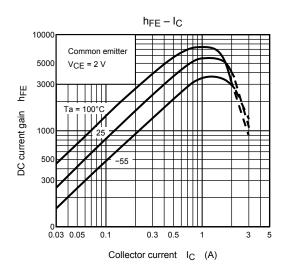
Marking

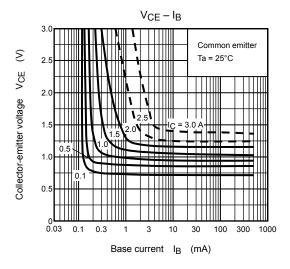


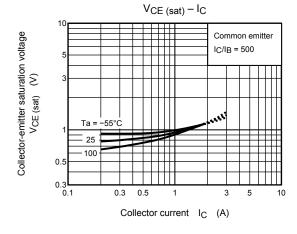
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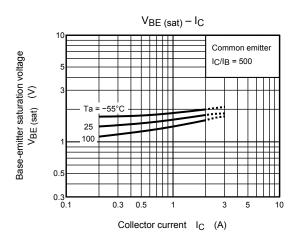






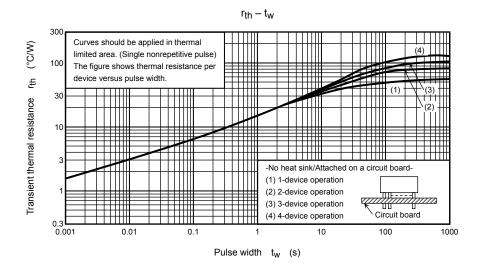


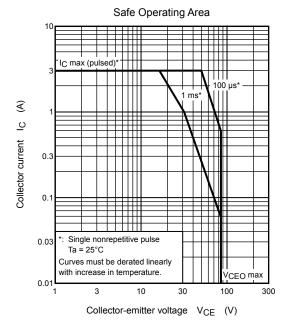


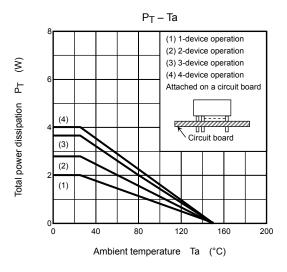


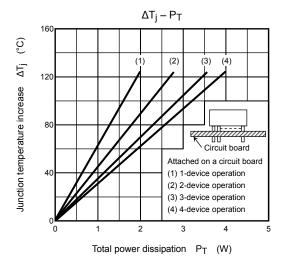
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